International Rectifier

50WQ04FN

SCHOTTKY RECTIFIER

5.5 Amp

$$I_{F(AV)} = 5.5 Amp$$
 $V_R = 40V$

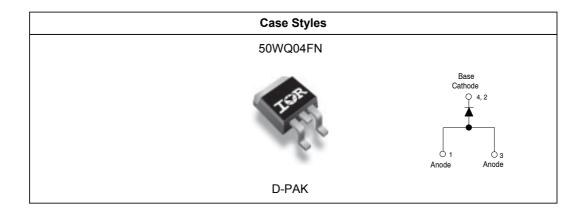
Major Ratings and Characteristics

| Chai | racteristics | 50WQ04FN | Units |
|--------------------|--------------------------------|------------|-------|
| I _{F(AV)} | Rectangular waveform | 5.5 | А |
| V _{RRM} | | 40 | V |
| I _{FSM} | @tp=5 µs sine | 550 | Α |
| V _F | @5 Apk, T _J = 125°C | 0.44 | V |
| Т | range | -40 to 150 | °C |

Description/ Features

The 50WQ04FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface moutable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





Voltage Ratings

| Part number | 50WQ04FN |
|--|----------|
| V _R Max. DC Reverse Voltage (V) | 40 |
| V _{RWM} Max. Working Peak Reverse Voltage (V) | 40 |

Absolute Maximum Ratings

| , to o o tate in a same of the | | | | | | |
|--|------------------------------------|---|-------|---|---|--|
| | Parameters | 50WQ | Units | Conditions | | |
| I _{F(AV)} | Max. Average Forward Current | 5.5 | Α | 50% duty cycle @ T _C = 135°C, r | , rectangular wave form | |
| | * See Fig. 5 | | | | | |
| I _{FSM} | Max. Peak One Cycle Non-Repetitive | 550 | Α | 5μs Sine or 3μs Rect. pulse | Following any rated load condition and with | |
| | Surge Current *See Fig. 7 | 90 | | 10ms Sine or 6ms Rect. pulse | rated V _{RRM} applied | |
| E _{AS} | Non-Repetitive Avalanche Energy | n-Repetitive Avalanche Energy 9 mJ T _J = 25 °C, I _{AS} = 1.5 Amps, L = 8 mH | | 3 mH | | |
| I _{AR} | Repetitive Avalanche Current | 1.2 | Α | Current decaying linearly to zero in 1 µsec | | |
| | | | | Frequency limited by T _J max. V _J | $_{A}$ = 1.5 x V_{R} typical | |

Electrical Specifications

| | Parameters | 50WQ | Units | | Conditions |
|-------------------|------------------------------|-------|-------|--|---------------------------------------|
| V _{FM} | Max. Forward Voltage Drop | 0.51 | V | @ 5A | T = 25 °C |
| | * See Fig. 1 (1) | 0.63 | V | @ 10A | $T_J = 25 ^{\circ}\text{C}$ |
| | | 0.44 | V | @ 5A | T _{_I} = 125 °C |
| | | 0.59 | V | @ 10A | 1 _J = 123 0 |
| I _{RM} | Max. Reverse Leakage Current | 3 | mA | T _J = 25 °C | V _P = rated V _P |
| | * See Fig. 2 (1) | 40 | mA | T _J = 125 °C | V _R - rated V _R |
| V _{F(TO} | Threshold Voltage | 0.27 | V | $T_J = T_J \text{ max.}$ | |
| r _t | Forward Slope Resistance | 26.77 | mΩ | | |
| C _T | Typical Junction Capacitance | 405 | pF | $V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25 °C | |
| L _s | Typical Series Inductance | 5.0 | nH | Measured lead to lead 5mm from package body | |

⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

| · · · · · · · · · · · · · · · · · · · | | | | |
|---------------------------------------|-------------------------------------|------------|---------|--------------------------|
| Parameters | | 50WQ | Units | Conditions |
| T _J | Max. Junction Temperature Range (*) | -40 to 150 | °C | |
| T _{stg} | Max. Storage Temperature Range | -40 to 150 | °C | |
| R _{thJC} | Max. Thermal Resistance | 3.0 | °C/W | DC operation *See Fig. 4 |
| | Junction to Case | | | |
| wt | Approximate Weight | 0.3 (0.01) | g (oz.) | |
| Case Style | | D-Pak | | Similar to TO-252AA |
| Device Marking | | 50WQ04FN | | |

 $[\]frac{\binom{*}{d}}{\frac{d}{d}} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

Bulletin PD-20524 rev. F 06/04

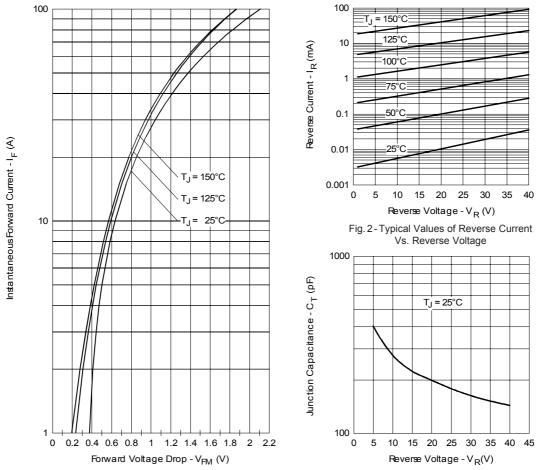


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

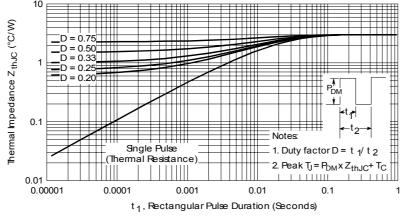


Fig. 4 - Maximum Thermal Impedance $Z_{th,JC}$ Characteristics

50WQ04FN

Bulletin PD-20524 rev. F 06/04

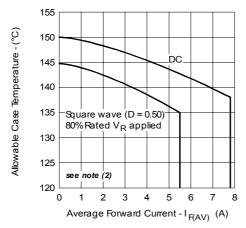


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

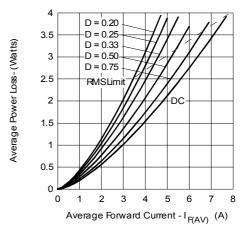


Fig. 6 - Forward Power Loss Characteristics

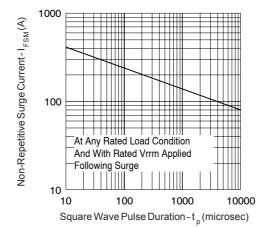
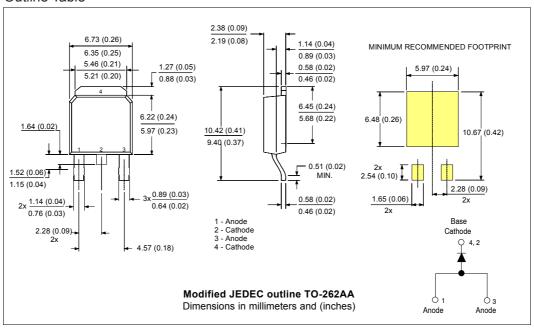


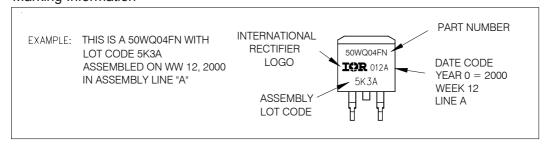
Fig. 7 - Maximum Non-Repetitive Surge Current

 $\begin{tabular}{ll} \textbf{(2)} & Formula used: $T_C = T_J - (Pd + Pd_{REV})x$ R_{thJC}; \\ & Pd = Forward Power Loss = $I_{F(AV)}x$ $V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); \\ & Pd_{REV} = Inverse Power Loss = $V_{R1}x$ $I_R(1-D)$; $I_R @ V_{R1} = 80\%$ rated V_R $I_R(1-D)$; $I_R(1-D)$;$

Outline Table



Marking Information



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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